

Electronics

Amplifier, Power, **1** W 2-18 GHz

Features

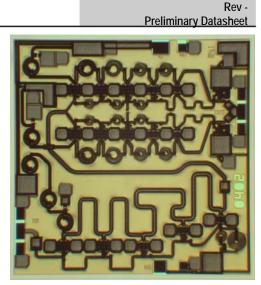
- I Watt Saturated Output Power Level
- Variable Drain Voltage (6-10V) Operation
- ♦ MSAG[®] Process

Description

The MAAP-000080-DIE000 is a 2-stage 1 W distributed power amplifier with on-chip bias networks. This product is fully matched to 50 ohms on both the input and output. It can be used as a power amplifier stage or as a driver stage in high power applications.

Fabricated using M/A-COM's repeatable, high performance and highly reliable GaAs Multifunction Self-Aligned Gate (MSAG[™])Process, each device is 100% RF tested on wafer to ensure performance compliance.

M/A-COM's MSAG[™] process features robust silicon-like manufacturing processes, planar processing of ion implanted transistors, multiple implant capability enabling power, low-noise, switch and digital FETs on a single chip, and polyimide scratch protection for ease of use with automated manufacturing processes. The use of refractory metals and the absence of platinum in the gate metal formulation prevents hydrogen poisoning when employed in hermetic packaging.



MAAP-000080-DIE000

Primary Applications

- Electronic Warfare
- Ultra Wideband (UWB)
- Test Instrumentation

Also Available in:

		SAMPLES	
Description	Plastic	Sample Board (Die)	Mechanical Sample (Die)
Part Number	MAAP-000080-PKG003	MAAP-000080-SMB004	MAAP-000080-MCH000

Electrical Characteristics: $T_B = 10^{\circ}C^1$, $Z_0 = 50\Omega$, $V_{DD} = 10V$, $I_{DQ} = 750mA^2$, $P_{in} = 22 \text{ dBm}$, $R_G = 130\Omega$

Parameter	Symbol	Typical	Units	
Bandwidth	f	2.0-18.0	GHz	
Output Power	Pout	30	dBm	
1-dB Compression Point	P1dB	29.5	dBm	
Small Signal Gain	G	11.5	dB	
Power Added Efficiency	PAE	11	%	
Input VSWR	VSWR	1.5:1		
Output VSWR	VSWR	1.8:1		
Gate Current	I _{GG}	5	mA	
Drain Current	I _{DD}	800	mA	

1. T_B = MMIC Base Temperature

2. Adjust V_{GG} between -2.6 and -1.2V to achieve specified Idq.

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Preliminary Datasheet

Maximum Ratings³

Parameter	Symbol	Absolute Maximum	Units
Input Power	P _{IN}	27.0	dBm
Drain Supply Voltage	V _{DD}	+12.0	V
Gate Supply Voltage	V _{GG}	-3.0	V
Quiescent Drain Current (No RF)	I _{DQ}	0.78	A
Quiescent DC Power Dissipated (No RF)	P _{DISS}	7.8	W
Junction Temperature	TJ	170	°C
Storage Temperature	T _{STG}	-55 to +150	°C

3. Operation beyond these limits may result in permanent damage to the part.

Recommended Operating Conditions⁴

Characteristic	Symbol	Min	Тур	Мах	Unit
Drain Voltage	V _{DD}	6.0	10.0	10.0	V
Gate Voltage	V_{GG}	-2.6	-2.0	-1.2	V
Input Power	P _{IN}		22.0	25.0	dBm
Thermal Resistance	Θ _{JC}		13.1		°C/W
MMIC Base Temperature	Τ _Β			Note 5	°C

4. Operation outside of these ranges may reduce product reliability.

5. MMIC Base Temperature = $170^{\circ}C - \Theta_{JC} * V_{DD} * I_{DQ}$

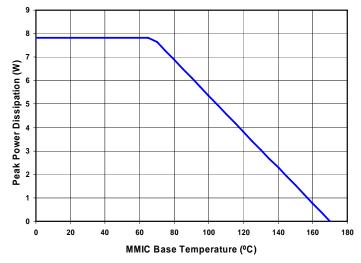


Operating Instructions

This device is static sensitive. Please handle with care. To operate the device, follow these steps.

- 1. Apply V_{GG} = -2.7 V, V_{DD} = 0 V.
- 2. Ramp V_{DD} to desired voltage, typically 10.0 V.
- 3. Adjust V_{GG} to set I_{DQ} , (approximately @ -2.0 V).
- 4. Set RF input.
- 5. Power down sequence in reverse. Turn V_{GG} off last.





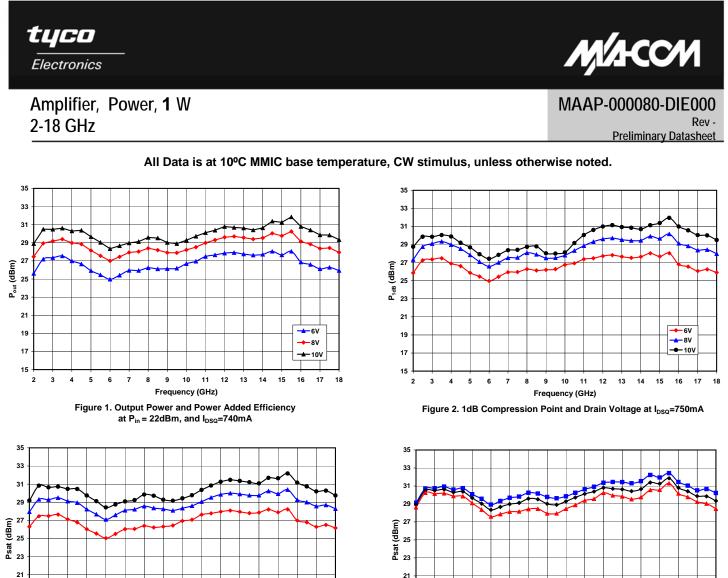
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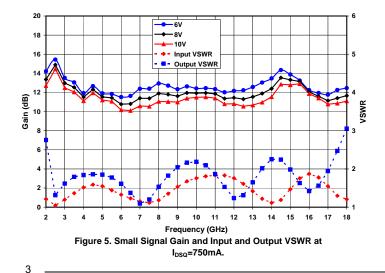
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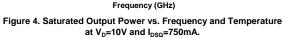
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21 19 - 8V 17 10 15 3 2 4 5 6 7 8 9 10 11 12 13 14 15 16 17 18 Frequency (GHz)

Figure 3. Saturated Output Power vs. Frequency and Drain Voltage



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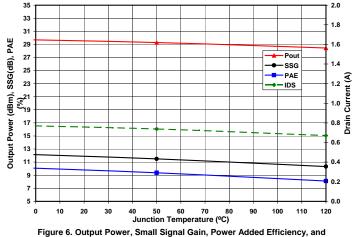


9 10 11 12 13 14 15 16 17 18

8

120%

+-50°C



Drain Current vs. Junction Temperature at 10V, 10GHz, and 750mA.

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18 20 22 24

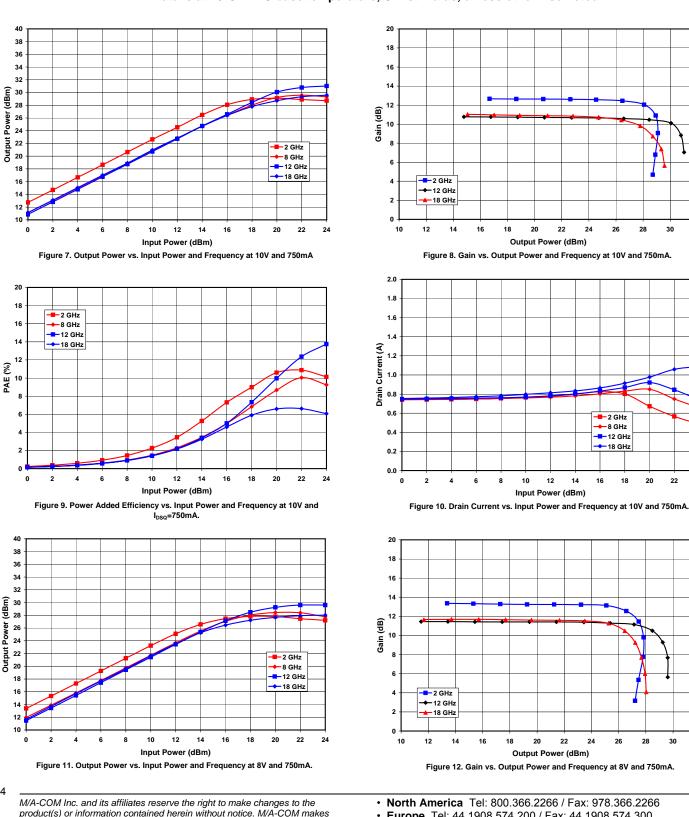
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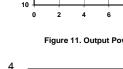


All Data is at 10°C MMIC base temperature, CW stimulus, unless otherwise noted.

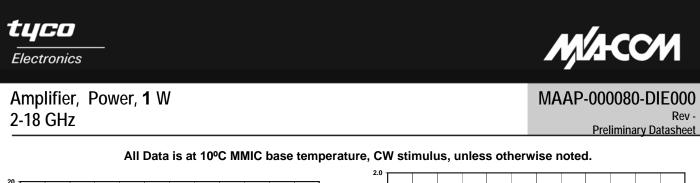
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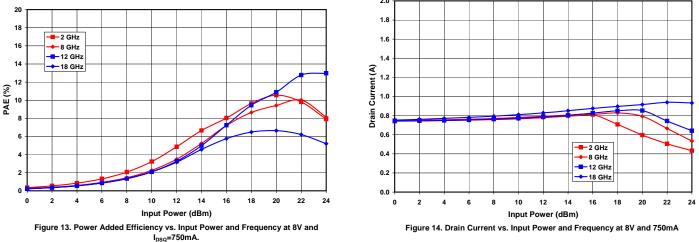
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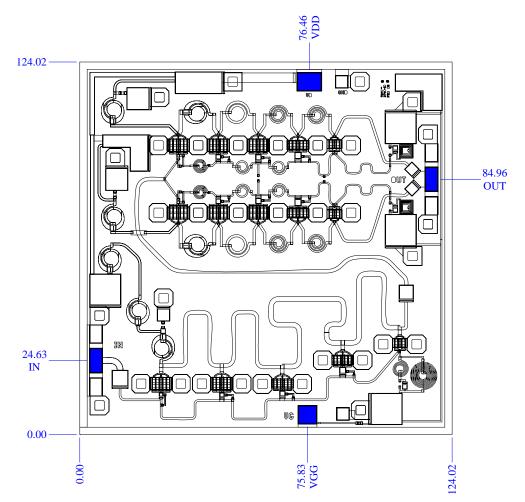
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Mechanical Information

Chip Size: 3.150 x 3.150 x 0.075 mm (124 x 124 x 3 mils)



Chip edge to bond pad dimensions are shown to the center of the bond pad (mils).

Figure 1. Die Layout

Bond Pad Dimensions

Pad	Size (μm)	Size (mils)
RF In and Out	100 x 200	4 x 8
DC Drain Supply Voltage VDD	200 x 150	8 x 6
DC Gate Supply Voltage VGG	150 x 150	6 x 6

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Assembly and Bonding Diagram

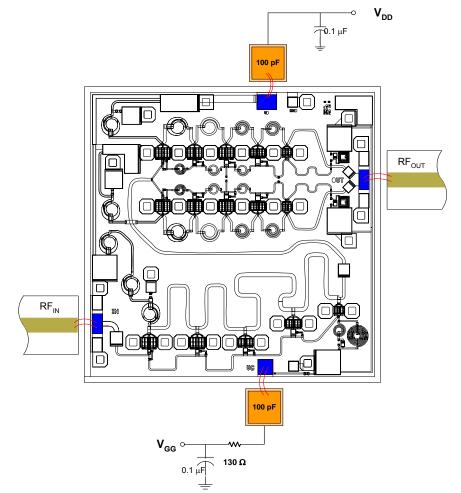


Figure 2. Recommended operational configuration. Wire bond as shown.

Assembly Instructions:

Die attach: Use AuSn (80/20) 1 mil. preform solder. Limit time @ 300 °C to less than 5 minutes.

Wirebonding: Bond @ 160 °C using standard ball or thermal compression wedge bond techniques. For DC pad connections, use either ball or wedge bonds. For best RF performance, use wedge bonds of shortest length, although ball bonds are also acceptable.

Biasing Note: Must apply negative bias to V_{GG} before applying positive bias to V_{DD} to prevent

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